Product data sheet

1. General description

Standard reverse recovery power diode in a TO-220F package.

2. Features and benefits

- · Low forward voltage drop
- Low leakage current
- · High voltage capability
- · High inrush current capability

3. Applications

- · Input rectifier
- Regulator diode

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit		
Absolute	maximum rating							
V _{RRM} repetitive peak reverse voltage					1600			
$I_{F(AV)}$	average forward current	$δ = 0.5$; square-wave pulse; $T_h \le 113$ °C; Fig. 1; Fig. 2; Fig. 3	8			А		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180 216			А		
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse				Α		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static ch	aracteristics							
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	-	1.2	V	
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	-	1.1	V	

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode	mb	K — A
2	K	cathode		001aaa020
mb	n.c.	mounting base; isolated		

6. Ordering information

TO-220F

WND08P16XQ

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		

Tube

7. Marking

WND08P16X

Table 4. Marking codes

Type number	Marking codes
WND08P16X	WND08P16X

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1600	V
V_{RWM}	crest working reverse voltage		1600	V
V_R	reverse voltage	DC	1600	V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_h \le 113$ °C; Fig. 1; Fig. 2; Fig. 3	8	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	216	А
T _{stg}	storage temperature		-55 to 150	°C
T _j	junction temperature		150	°C

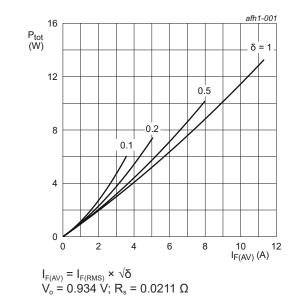
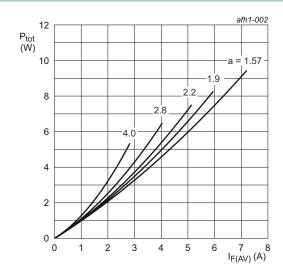


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

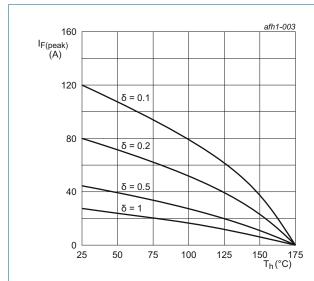


a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.934 V; R_s = 0.0211 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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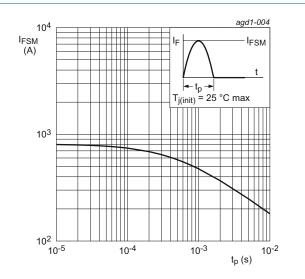


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

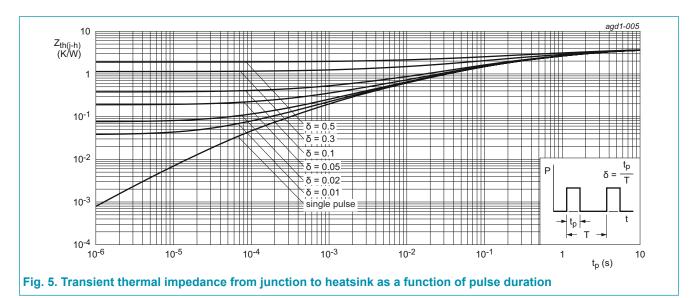
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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	<u>Fig. 5</u>	-	-	3.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



10. Isolation characteristics

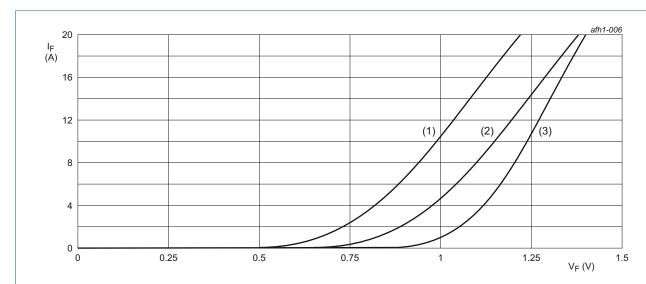
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	PF

11. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>	-	-	1.2	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>	-	-	1.1	V
I _R	reverse current	V _R = 1600 V; T _j = 25 °C	-	-	50	μA
		V _R = 1600 V; T _j = 150 °C	-	-	1.5	mA

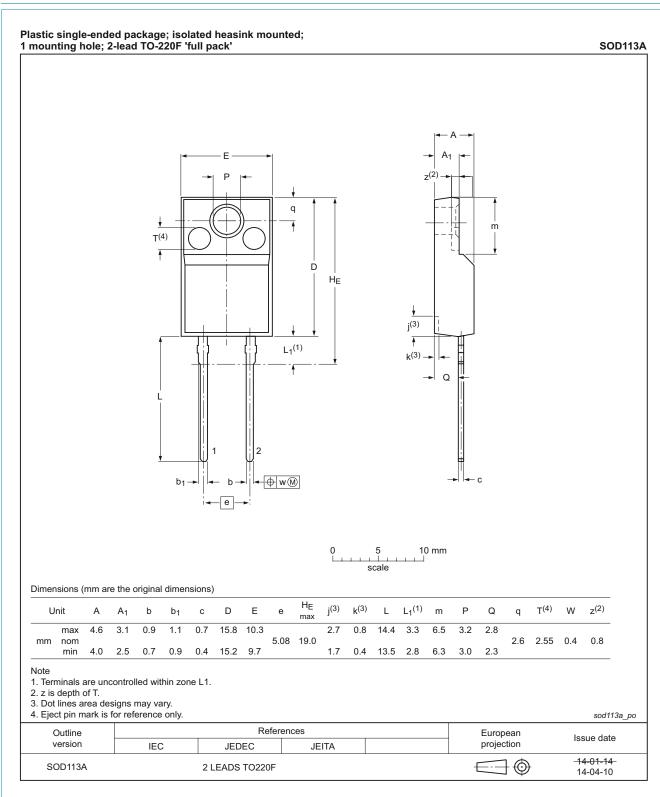


 $V_o = 0.934 \text{ V}; R_s = 0.0211 \Omega$

(1) $T_j = 150$ °C; typical values (2) $T_j = 150$ °C; maximum values (3) $T_j = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

12. Package outline



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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